Magnetic and Ferroelectric Ordering in the TbMnO$_3$ Film

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Measurements of magnetization and electric polarization performed for the TbMnO$_3$ film grown onto the single crystal [100] SrTiO$_3$ substrate using magnetron sputtering technique exhibit series of anomalies related to the magnetic and electric ordering of the Tb$^{3+}$ and Mn$^{3+}$ sublattices. The detailed temperature dependences of the electric polarization and dielectric constant of the TbMnO$_3$ film have shown that the ferroelectric phase appears below 30 K in magnetic field $H > 1$ T applied in-plane and out-of-plane of the film.

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1. Introduction

Among all of the known multiferroic materials, the TbMnO$_3$ manganite has attracted considerable scientific attention in the last years due to strong coupling between ferroelectricity and magnetism [1, 2]. The magnetoelectric and magneto-capacitive effects observed in the TbMnO$_3$ ferroelectric can be used in novel magnetoelectric devices, in which the magnetic properties are electrically controlled and vice versa.

In several works [2−5] the structural, electric, thermal, and magnetic properties of the TbMnO$_3$ single crystals as a function of temperature and magnetic field have been studied. According to a specific heat and neutron diffraction study of the TbMnO$_3$ single crystal, the anomalies observed at 7 and 41 K are attributed to the antiferromagnetic ordering of the Tb$^{3+}$ and Mn$^{3+}$ moments, respectively. Mn spins order in a sinusoidal incommensurate structure. A spontaneous electrical polarization in the single crystal samples was observed below 28 K, when the magnetic structure transforms from a sinusoidal incommensurate to a spiral antiferromagnetic one that testifies about very strong magnetoelectric coupling.

In works [6, 7] the magnetic properties of the TbMnO$_3$ thin films have been studied. Neutron scattering measurements [7] have shown the presence of an intrinsic ferromagnetic ordering in an antiferromagnetic multiferroic TbMnO$_3$ film at low temperatures. Since this antiferromagnet is piezomagnetic, the epitaxial strain was shown to induce a ferromagnetic moment in this film [6], whereas the electric polarization in the TbMnO$_3$ films was not investigated.

In this paper, the measurements of ferroelectricity and magnetization of the TbMnO$_3$ film have been performed that has allowed to observe the evolution of magnetic and electric properties of TbMO$_3$ near the magnetic and ferroelectric phase transitions as well as their control by the application of magnetic and/or electric fields.

2. Preparation and measurement techniques

The investigated TbMnO$_3$ film, 150 nm thick, was grown using magnetron sputtering of target onto [100] SrTiO$_3$ single crystal substrate in argon−oxygen gas atmosphere. The temperature of substrate was 650°C and deposition time was 3 h.

Figure 1 presents X-ray diffraction structural analysis performed with low (16 h) and high (2 h) rate. It clearly shows diffraction peaks corresponding to cubic [100] oriented SiTiO$_3$ substrate (at $2\theta = 22.8$ and 46.5°) and slightly shifted to the left orthorombic [001] TbMnO$_3$ film (at $2\theta = 23.8$ and 46.8°). The displacement of peaks corresponding to substrate and film could be justified by minor offset in stoichiometric composition of the film or mismatch of lattice parameters of the film and the substrate. Bulk TbMnO$_3$ has the orthorhombic perovskite structure, which has lattice parameters of 0.393 nm in-plane and 0.370 nm out-of-plane [8], while the film has the perovskite structure with an out-of-plane lattice parameter of 0.372 nm. Therefore, we conclude the film is compressively strained by the substrate resulting in the tetragonally distorted orthorhombic phase of TbMnO$_3$. To find out the origin of the peak of 37.5° the more detailed structural analysis must be performed.

The magnetic measurements were carried out using a commercial SQUID magnetometer in temperature range of 5−300 K in magnetic fields up to 5 T.

Electric polarization was measured both at fixed magnetic field and fixed temperature using Keithley 6423 electrometer at temperatures of 5−45 K and in magnetic fields up to 8 T. For measurements of the electric polarization, the silver contacts were plotted onto the widest faces of the rectangle $7 \times 3$ mm TbMnO$_3$ film. Magnetic field was measured by conventional Hall sensor, temperature was controlled by thermometer mounted directly on insert connected to precision Lakeshore 340 temperature controller. The magnetocapacitance measurements have
been performed by high precision bridge AH2550A with 1 kHz frequency.

3. Experimental results and discussion

Temperature dependence of susceptibility, $M/H$, of the TbMnO$_3$ film in magnetic field of 6 kOe is presented in Fig. 2. The diamagnetic contribution arising from the substrate measured in a separate experiment was subtracted from the raw magnetization. The $M/H$ dependence shows a distinct anomaly at 45 K. This anomaly is close to the anomalies of $C(T)$ and $M(T)$ observed in the TbMnO$_3$ single crystal [2], which correspond to the magnetic phase transitions in Mn$^{3+}$ sublattice.

However, the $M/H(T)$ dependence did not detect the anomaly observed at 27 K in the single crystal [2] and connected with an occurrence of the ferroelectric phase, followed by an incommensurate to commensurate magnetic phase transition in the Mn sublattice.

The hysteretic behavior in the TbMnO$_3$ film was observed at low temperatures in the field range of ±20 kOe. These measurements show that an antiferromagnetic multiferroic TbMnO$_3$ film exhibits an intrinsic ferromagnetic order at low temperatures (Fig. 3).

This is in agreement with the polarized neutron reflectometry measurements data [7]. One of possible origin of the observed ferromagnetism in film is presumed to be the coupling between magnetization and film strain imposed by the substrate [6].

The measurements of temperature dependence of reciprocal susceptibility display the paramagnetic Curie–Weiss temperatures equal to about 7 K and 40 K for Tb$^{3+}$ and Mn$^{3+}$ ions, respectively (Fig. 4).

The electric polarization of the TbMnO$_3$ film as a function of temperature at different magnetic fields applied along the $a$ (in-plane) and $c$ (out-of-plane) configurations is presented in Fig. 5. Magnetoelastic measurements of SrTiO$_3$ substrate were performed in a separate experiment, and the contribution arising from the substrate was subtracted from the raw polarization. It is seen that the electric polarization appears below 30 K in applied magnetic field of $H > 1$ T that is related to the occurrence of the ferroelectric phase.

There is no more difference between ferroelectric signal and noise of substrate above 35 K. It is seen that
the electric polarization depends strongly on both value and direction of magnetic field relative to the crystallographic axes. The electric polarization value increases with decreasing temperature and as magnetic field is increased. The onset temperature of ferroelectric ordering ($T_{FE}$) in magnetic field $H \perp a$ (Fig. 5b) is almost independent of field in contrast to $T_{FE}$ in magnetic field applied along the $a$ axis (Fig. 5a) which shifts towards high temperatures with increasing magnetic field. The magnetic-field-induced electric polarization in magnetic field $H \perp a$ exceeds one for magnetic field applied along the $a$ axis. The significant increase of polarization is observed below 7 K, especially for $H \perp a$ direction (Fig. 5). This data are in line with the measurements of dielectric properties (Fig. 4), where the saturation appears below 10 K.

We have also performed measurements of the dielectric constant at 1 kHz frequency as a function of temperature at magnetic fields applied perpendicular to the film plane.

Figure 6 presents the temperature variation of the dielectric constant, $\Delta \varepsilon/\varepsilon(0)$, in magnetic fields of 1 and 8 T applied perpendicular to the film plane. The dielectric constant value starts to be observed below 30 K that clearly shows the occurrence of ferroelectric ordering. The dielectric constant saturation below 10 K corresponds to an antiferromagnetic ordering of Tb$^{3+}$ ions. The $\Delta \varepsilon/\varepsilon(T)$ behavior shows a slight magnetic field effect. These results are in agreement with early obtained data for the single crystal [4].

4. Conclusions

In this paper, susceptibility and electric polarization measurements for the TbMnO$_3$ film have been carried out. The magnetic and ferroelectric phase transitions were determined from the anomalies of magnetic and electric properties as a function of temperature, respectively.

Magnetic field dependences of magnetization show a manifestation of the low temperature ferromagnetism in the antiferromagnetic TbMnO$_3$ film grown on [001] SrTiO$_3$ substrate. However, they do not display signs of a phase transition related to the onset of ferroelectricity observed in the TbMnO$_3$ single crystal. The measurements of temperature dependences of both the electric polarization and dielectric constant of the TbMnO$_3$ film have been performed. It has been found that the charge ordering and ferroelectric phase appears below 30 K and significantly raises coming through 10 K.

It should be noted that the temperature of ferroelectric phase transition slightly shifts towards high temperatures with applying or changing the direction of magnetic field.

References